

Schottky Diode

DSA20C100PN

preliminary

V_{RRM}	=	100 V
I _{FAV}	<i>=</i> 2x	10 A
V۶	=	0.71 V

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

Part number

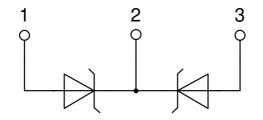
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Backside: isolated



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Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
 Low voltage peaks for reduced
- protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-220FP

- Isolation Voltage: 2500 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

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Schottky					Ratings		
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse block	ng voltage	$T_{vJ} = 25^{\circ}C$			100	V
V _{RRM}	max. repetitive reverse blocking v	oltage	$T_{vJ} = 25^{\circ}C$			100	V
I _R	reverse current, drain current	$V_{R} = 100 V$	$T_{VJ} = 25^{\circ}C$			200	μA
		$V_{R} = 100 V$	$T_{vJ} = 125^{\circ}C$			2	mA
VF	forward voltage drop	$I_{F} = 10 \text{ A}$	$T_{vJ} = 25^{\circ}C$			0.89	V
		$I_{F} = 20 \text{ A}$				1.04	V
		$I_{F} = 10 \text{ A}$	T _{vJ} = 125°C			0.71	V
		$I_{F} = 20 \text{ A}$				0.87	V
IFAV	average forward current	T _c = 140°C	T _{vJ} = 175°C			10	Α
		rectangular d = 0.5					1 1 1
V _{F0}	threshold voltage		T _{vJ} = 175°C			0.45	V
r _F	slope resistance } for power lo	oss calculation only				16.1	mΩ
R _{thJC}	thermal resistance junction to cas	e				4.5	K/W
R _{thCH}	thermal resistance case to heatsir	nk			0.5		K/W
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			35	W
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_R = 0 V$	$T_{vJ} = 45^{\circ}C$			240	Α
C	junction capacitance	$V_{\rm B} = 12 V$ f = 1 MHz	$T_{vJ} = 25^{\circ}C$		96		pF

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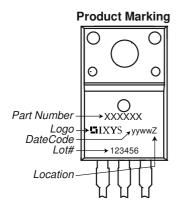
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Package TO-220FP					Ratings			
Symbol	Definition	Conditions			min.	typ.	max.	Unit
	RMS current	per terminal					35	А
T _{vj}	virtual junction temperature				-55		175	°C
T _{op}	operation temperature				-55		150	°C
T _{stg}	storage temperature				-55		150	°C
Weight						2		g
M _D	mounting torque				0.4		0.6	Nm
F _c	mounting force with clip				20		60	Ν
d _{Spp/App}	creepage distance on surface sti	riking distance through air	terminal to terminal	1.6	1.0			mm
d _{Spb/Apb}		iking distance through an	terminal to backside	2.5	2.5			mm
V	isolation voltage	t = 1 second			2500			V
		t = 1 minute	50/60 Hz, RMS; liso∟ ≤ 1 mA		2100			V



Part description

- D = Diode S = Schottky Diode

- A = low VF 20 = Current Rating [A] C = Common Cathode 100 = Reverse Voltage [V] PN = TO-220ABFP (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA20C100PN	DSA20C100PN	Tube	50	503516

Similar Part	Package	Voltage class
DSA20C100PB	TO-220AB (3)	100

Equiva	alent Circuits for	Simulation	* on die level	$T_{VJ} = 175^{\circ}C$
)[R	Schottky		
V _{0 max}	threshold voltage	0.45		V
$\mathbf{R}_{0 \max}$	slope resistance *	12.9		mΩ

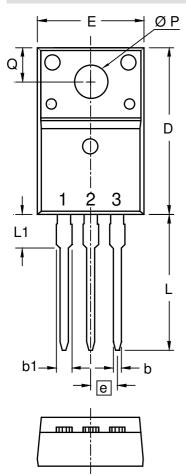
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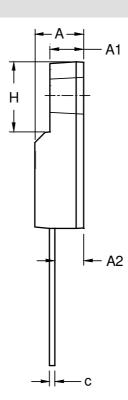


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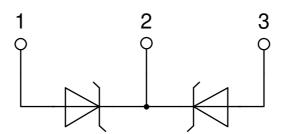
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Outlines TO-220FP





Dim	Millim	neters	Inc	hes		
Dim.	min max min		min	max		
А	4.50	4.90	0.177	0.193		
A1	2.34	2.74	0.092	0.108		
A2	2.56	2.96	0.101	0.117		
b	0.70	0.90	0.028	0.035		
С	0.45	0.60	0.018	0.024		
D	15.67	16.07	0.617	0.633		
Е	9.96	10.36	0.392	0.408		
е	2.54	BSC	0.100	BSC		
Н	6.48	6.88	0.255	0.271		
L	12.68	13.28	0.499	0.523		
L1	3.03	3.43	0.119	0.135		
ØΡ	3.08	3.28	0.121	0.129		
Q	3.20	3.40	0.126	0.134		



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